

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





SOT-23 Formed SMD Package

CMBD1201, 1202, 1203 CMBD1204, 1205

SILICON PLANAR EPITAXIAL HIGH SPEED DIODES

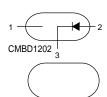
CMBD1201, 1202, are all single diodes CMBD1203 is a dual diode, in series CMBD1204 is a dual diode, common cathode CMBD1205 is a dual diode, common anode

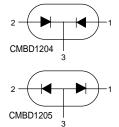
 Marking
 CMBD1203
 26

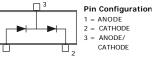
 CMBD1201 - 24
 CMBD1204
 27

 CMBD1202 - 25
 CMBD1205
 28

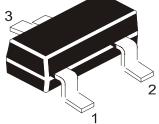
2 1 1 CMBD1201 -







CMBD1203

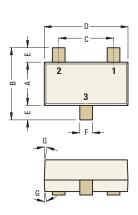


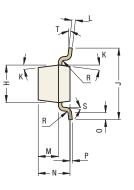
ABSOLUTE MAXIMUM RATINGS (per diode)

Continuous reverse voltage	V_R	max.	75 V
Repetitive peak reverse voltage	V_{RRM}	max.	100 V
Repetitive peak forward current	I_{FRM}	max.	500 mA
Forward current	I_F	max.	215 mA
Junction temperature	T_{j}	max.	150 ° C
Forward voltage at $I_F = 10 \text{ mA}$	\check{V}_F	<	0.855 V

Reverse recovery time when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ;				
measured at $I_R = 1 \text{ mA}$	t_{TT}	<	4	ns
RATINGS (per diode) (at $T_A = 25$ °C unless otherw	ise specified)			
Limiting values	1			
Continuous reverse voltage	V_R	max.	75	V
Repetitive peak reverse voltage	V_{RRM}	max.	100	V
Repetitive peak forward current	I_{FRM}	max.	500	mA
Forward current	I_F	max.	215	mA
Non-repetitive peak forward current (per crystal)	1			
$t = 1 \mu s$	I_{FSM}	max.	4	\boldsymbol{A}
t = 1 ms	I_{ESM}	max.	1.0	\boldsymbol{A}
t = 1 s	I_{ESM}	max.	0.5	\boldsymbol{A}
Storage temperature	Tstg	-55 to	+150	° C
Junction temperature	Τj	max.		$^{\circ}$ C
1	J			
THERMAL RESISTANCE				
From junction to ambient	$R_{th\ j-a}$	=	500	K/W
J	ar j a			
CHARACTERISTICS (per diode)				
$T_i = 25$ °C unless otherwise specified				
Forward voltage				
$I_F = 10 \text{ mA}$	V_F	<	0.855	V
$I_F = 200 \text{ mA}$	V_F	<	1.10	V
	. 1.			
Deviance examinate				
Reverse currents	7_		9.5	4
$V_R = 20 V$	I_R	<		nA
$V_R = 75 V$	I_R	<		μA
$V_R = 25 \ V; \ T_j = 150 \ ^{\circ}C$	I_R	<	30	μA
Forward recovery voltage				
$I_F = 10 \text{ mA}; t_p = 20 \text{ ns}$	V_{fr}	<	1.75	V
Recovery charge				
$I_F = 10 \text{ mA to } V_R = 5V; R = 100 \Omega$	$Q_{\mathbf{S}}$	<	45	рC
	vs			r
Diode capacitance	C -		a	E
$V_R = 0$; $f = 1 MHz$	C_d	<	۷	pF
Reverse recovery time when switched from				
$I_F=10~mA~to~I_R=10~mA;~R_L=100~\Omega;$				
measured at $I_R = 1 \text{ mA}$	t_{IT}	<	4	ns

SOT-23 SMD Plastic Package

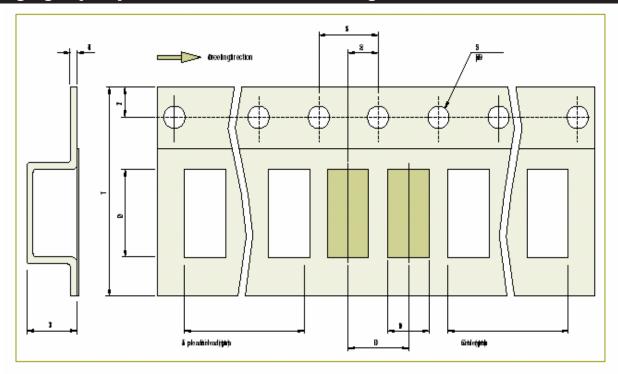




DIM	Min	Max			
Α	1.20	1.40			
В	2.10 2.64				
С	1.85	1.95			
D	2.80	3.04			
Е	0.54	0.67			
F	0.30	0.50			
G	3°				
Н	_	1.30			
J	2.10	2.64			
	0	0.			

DIM	Min	Max			
K	7	0			
L	0.08 0.20				
M	0.58	0.62			
N	0.70	1.02			
0	0.21	_			
Р	0.02	0.15			
R	_	0.08			
S	2°	8°			
Т	2°	10°			

Packaging Tape Specifications for SMD Packages



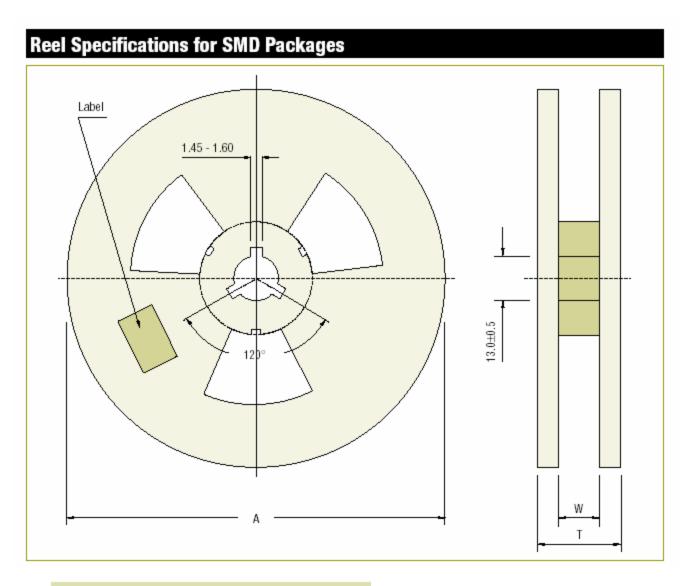
SMD Tape Specifications (8-12 mm)

Device	D1	D2	D3	Tí	T2	T3	T4	S1	S2	S3
						Max	Max			Dia
	mm	mm	mm	mm	mm	mm	mm	mm	mm	mm
S0T-23	3.2±0.1	2.8±0.1	4.0±0.1	8.0±0.2	1.75±0.1	1.60	0.35	4.0±0.1	2.0±0.1	1.5±0.1

Packaging Specifications ...

T & A: Tape and Ammo Pack; T & R: Tape and Reel; Bulk: Loose in Poly Bags; Tube: Tube and Carton; K: 1,000

Package / Case Type	Packaging Type	Std. Packing		Inner Carton		Outer Carton			
		Oty	Qty Size L x W x H Gross Weight		Qty	Size L x W x H	Gross Weight		
				(cm)	(Kg)		(cm)	(Kg)	
S0T-23	T&R	3,000	15K	19 x 19 x 8	0.6	51K	23 x 23 x 23	2.2	
	T&R	3,000	15K	19 x 19 x 8	0.6	408K	48 x 48 x 51	20.2	
	T&R	10,000	50K	35.5 x 35.5 x 8.9	2.4	350K	48 x 48 x 51	19.2	



Reel Specifications

Package	Tape	Reel Dia.	Devices	Inside	Reel
	Width		per Reel	Thickness	Thickness
		A - Max	and MOQ	W	T - Max
SOT-23	8	180	3,000	8.4±2	14.4
	8	330	10,000	8.4±2	14.4

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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